

## SILICON TRANSISTOR ARRAY

# $\mu$ PA1458

## NPN SILICON POWER TRANSISTOR ARRAY LOW SPEED SWITCHING USE (DARLINGTON TRANSISTOR) INDUSTRIAL USE

#### **DESCRIPTION**

The  $\mu$ PA1458 is NPN silicon epitaxial Darlington Power Transistor Array that built in Surge Absorber and 4 circuits designed for driving solenoid, relay, lamp and so on.

#### **FEATURES**

- Surge Absorber (C B) built in.
- Easy mount by 0.1 inch of terminal interval.
- High hee for Darlington Transistor.

#### ORDERING INFORMATION

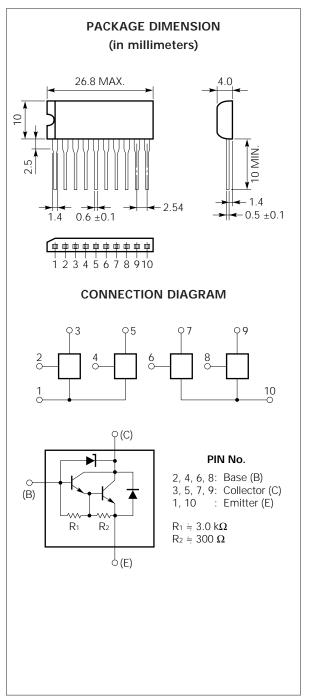
Part Number	Package	Quality Grade		
μPA1458H	10 Pin SIP	Standard		

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Collector to Base Voltage	$V_{\text{CBO}}$	60 ±10	V
Collector to Emitter Voltage	$V_{\text{CEO}}$	60 ±10	V
Emitter to Base Voltage	$V_{EBO}$	7	V
Surge Sustaining Energy	Eceo(sus)	25	mJ/unit
Collector Current (DC)	Ic(dc)	±5	A/unit
Collector Current (pulse)	IC(pulse)*	±10	A/unit
Collector Current	ICBS(DC)	5	mA/unit
Base Current (DC)	IB(DC)	0.5	A/unit
Total Power Dissipation	P <sub>T1</sub> **	3.5	W
Total Power Dissipation	P <sub>T2</sub> ***	28	W
Junction Temperature	Tj	150	.C
Storage Temperature	Tstg -5	55 to +15	0 °C

- \* PW  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  10 %
- \*\* 4 Circuits, Ta = 25 °C
- \*\*\* 4 Circuits, Tc = 25 °C



The information in this document is subject to change without notice.

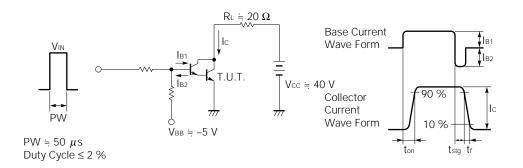


## ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Collector Leakage Current	Ices			10	μΑ	Vce = 40 V	
Emitter Leakage Current	Ієво			10	mA	VEB = 5 V, Ic = 0	
Collector to Emitter Sustaining Voltage	VCEO(sus)	50	60	70	V	Ic = 3 A, L = 1 mH	
DC Current Gain	h <sub>FE1</sub> *	2000	7000	20000	_	Vce = 2 V, Ic = 2 A	
DC Current Gain	h <sub>FE2</sub> *	500	3000		_	Vce = 2 V, Ic = 4 A	
Collector Saturation Voltage	VcE(sat) *		0.9	1.5	V	Ic = 2 A, I <sub>B</sub> = 2 mA	
Base Saturation Voltage	V <sub>BE(sat)</sub> *		1.6	2	V	Ic = 2 A, I <sub>B</sub> = 2 mA	
Turn On Time	ton		1		μs	Ic = 2 A	
Storage Time	tstg		7		μs	$\begin{array}{l} I_{B1} = -I_{B2} = 2 \text{ mA} \\ V_{CC} \doteqdot 40 \text{ V}, \text{ RL} \doteqdot 20 \Omega \\ \text{See test circuit} \end{array}$	
Fall Time	tr		2		μs		

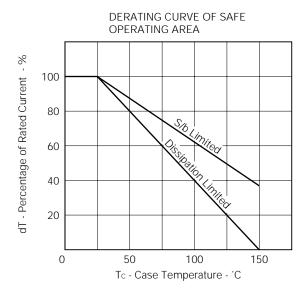
<sup>\*</sup> PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2 % / pulsed

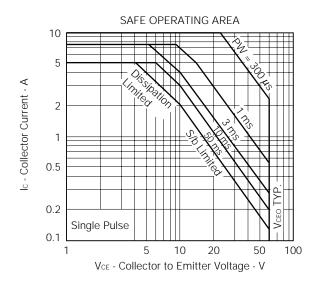
## SWITCHING TIME TEST CIRCUIT



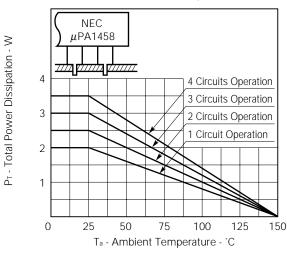


## TYPICAL CHARACTERISTICS (Ta = 25 °C)

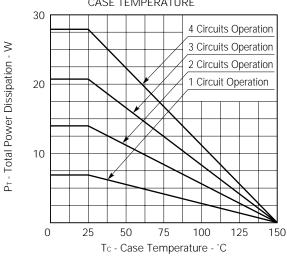




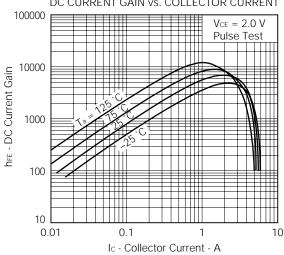




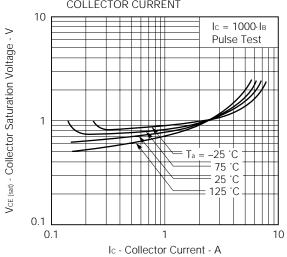




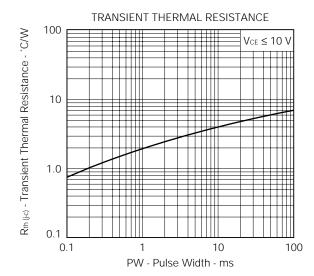
## DC CURRENT GAIN vs. COLLECTOR CURRENT

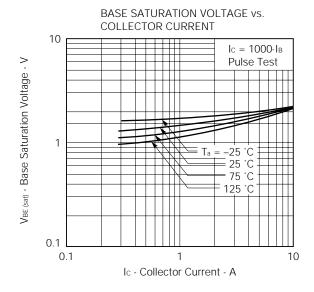


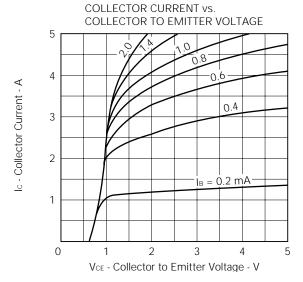
#### COLLECTOR SATURATION VOLTAGE vs. **COLLECTOR CURRENT**













# REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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